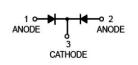


Features:

- Very Small Plastic SMD Package
- High Switching Speed: 4ns (Max.)
- Continuous Reverse Voltage: 75V (Max.)
- Repetitive Peak Reverse Voltage: 85V (Max.)
- Repetitive Peak Forward Current: 500mA (Max.)





Applications:

High-speed switching in e.g. surface mounted circuits

SOT-523

Max. Rating @ TA = 25°C unless otherwise specified

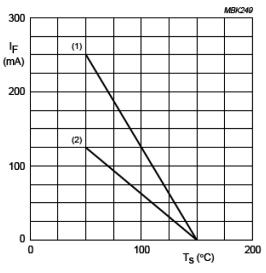
Parameter		Symbol	Limits	Unit
Peak repetitive reverse voltage		VRRM	85	V
Continuous reverse voltage		VR	75	V
RMS reverse voltage		Vr(rms)	53	V
Forward continuous current (Max.)	Single diode loaded Both diodes loaded	Іғм	150 75	mA
Repetitive peak forward current		IFRM	500	mA
Non-repetitive peak forward surge cur	rent @t = 1µs @t = 1ms @t = 1s	IFSM	4 1 0.5	А
Total power dissipation Ts = 90°C; one	e diode loaded	P _{tot}	170	mW
Junction and storage temperature		Т _{ј,} Тѕтс	-65 to +150	°C

Electrical Characteristics @ TA = 25°C unless otherwise specified

	•	•			
Parameter	Symbol	Conditions	Min.	Max.	Unit
Leakage current	lR	VR = 25V VR = 75V VR = 25V, Tj = 150°C VR = 75V, Tj = 150°C	-	30 2 60 100	nA μA μA μA
Forward voltage	VF	IF = 1mA IF = 10mA IF = 50mA IF = 150mA	-	0.715 0.855 1 1.25	V
Diode capacitance	Сп	V _R =0V, f=1MHz	-	1.5	pF
Forward recovery voltage	V _{ff}	IF = 10mA, t _r = 20ns	-	1.75	V
Reverse recovery time	trr	IF = IR = 10mA, Irr = $0.1 \times IR$, RL = 100Ω	-	4	ns

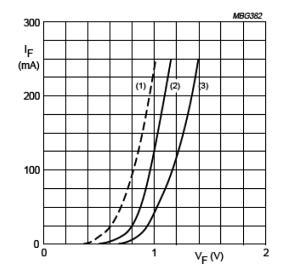


Typical Characteristics @ TA = 25°C unless otherwise specified



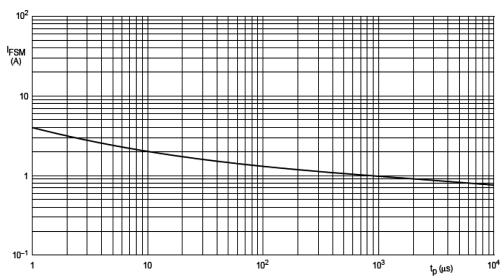
- (1) One diode loaded.
- (2) Both diodes loaded.

Fig.2 Maximum permissible continuous forward current per diode as a function of soldering point temperature.



- T_i = 150 °C; typical values.
- (2) T_i = 25 °C; typical values.
- (3) T_i = 25 °C; maximum values.

Fig.3 Forward current as a function of forward voltage.



Based on square wave currents. T_i = 25 °C prior to surge.

Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration.



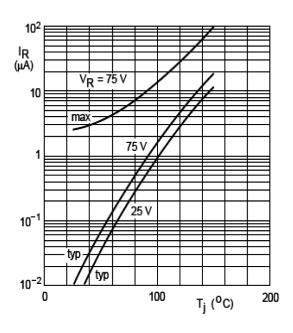
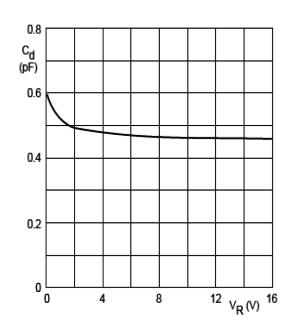


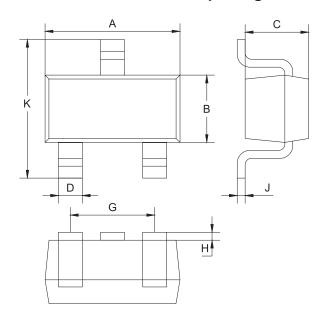
Fig.5 Reverse current as a function of junction temperature.



f = 1 MHz; $T_i = 25 °C$.

Diode capacitance as a function of reverse voltage; typical values.

Plastic surface mounted package

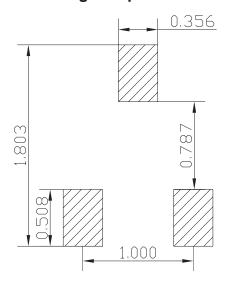


SOT-523		
Dim	Min	Max
А	1.5	1.7
В	0.75	0.85
С	0.6	0.8
D	0.15	0.3
G	0.9	1.1
Н	0.02	0.1
J	0.1Typical	
K	1.45	1.75
All Dimensions in mm		





Soldering Footprint



Package Information

Device	Package	Shipping
BAV70T-7-F	SOT-523	3,000 / Tape & Reel

Unit: mm

Part Number Table

Description	Part Number	
High-speed double Diode	BAV70T-7-F	

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